# Miniature Reflective Object Sensor

#### Features

- Phototransistor Output
- No Contact Surface Sensing
- Miniature Package
- Lead Form Style: Gull Wing
- Two Leadform Options:
  - Through Hole (QRE1113)
  - SMT Gull Wing (QRE1113GR & QRE1114GR)
- Two Packaging Options:
  - Tube (QRE1113)
  - Tape and Reel (QRE1113GR & QRE1114GR)

## **MAXIMUM RATINGS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Value	Unit
T <sub>OPR</sub>	Operating Temperature	-40 to +85	°C
T <sub>STG</sub>	Storage Temperature	-40 to +90	°C
T <sub>SOL-I</sub>	Soldering Temperature (Iron) (Notes 2, 3, 4)	240 for 5 s	°C
T <sub>SOL-F</sub>	Soldering Temperature (Flow) (Notes 3, 4)	260 for 10 s	°C

#### EMITTER

١ <sub>F</sub>	Continuous Forward Current	50	mA
V <sub>R</sub>	Reverse Voltage	5	V
I <sub>FP</sub>	I <sub>FP</sub> Peak Forward Current (Note 5)		Α
PD	Power Dissipation (Note 1)	75	mW

#### SENSOR

V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>ECO</sub>	Emitter-Collector Voltage	5	V
Ι <sub>C</sub>	Collector Current	20	mA
PD	P <sub>D</sub> Power Dissipation (Note 1)		mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

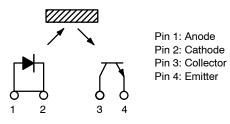
- 1. Derate power dissipation linearly 1.00 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) from housing.
- 5. Pulse conditions: tp = 100  $\mu$ s; T = 10 ms.

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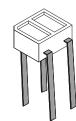
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#### REFLECTIVE RECTANGULAR SURFACE MOUNT CASE 100CY



#### REFLECTIVE RECTANGULAR THROUGH HOLE CASE 100AQ

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>	
QRE1113	Reflective Rectangular (Through Hole)	1600 / Tube	
QRE1113GR & QRE1114GR	Reflective Rectangular (Surface Mount)	1000 / Tape & Reel	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### ELECTRICAL/OPTICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
INPUT DIO	DE						
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 20 mA			1.2	1.6	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>R</sub> = 5 V				10	μA
$\lambda_{PE}$	Peak Emission Wavelength	I <sub>F</sub> = 20 mA			940		nm
	RANSISTOR						
Ι <sub>D</sub>	Collector-Emitter Dark Current	I <sub>F</sub> = 0 mA, V <sub>CE</sub> = 20 V				100	nA
COUPLED							
I <sub>C(ON)</sub>	On-State Collector	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V (Note 6)	QRE1113 & QRE1113GR	0.10	0.90		mA
	Current		QRE1114GR	0.30		0.60	mA
I <sub>CX</sub>	Cross-Talk Collector Current	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 5 V (Note 7)				1	μA
V <sub>CE(SAT)</sub>	Saturation Voltage	I <sub>F</sub> = 20 mA, I <sub>C</sub> = 50 μA (Note 6)			1	0.3	V
t <sub>r</sub>	Rise Time	$V_{CC}$ = 5 V, $I_{C(ON)}$ = 100 $\mu$ A, $R_L$ = 1 k $\Omega$			20		μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20

μs

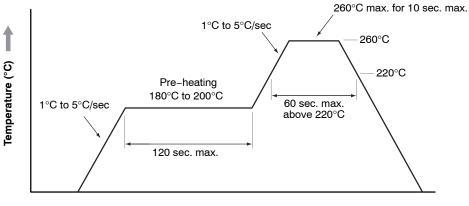
6. Measured using an aluminum alloy mirror at d = 1 mm.

7. No reflective surface at close proximity.

Fall Time

t<sub>f</sub>

## **REFLOW PROFILE**



Time (seconds)

Figure 1. Reflow Profile

## **TYPICAL PERFORMANCE CURVES**

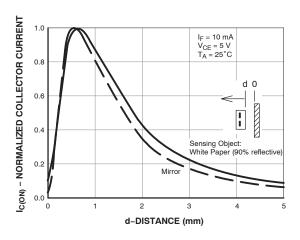


Figure 2. Normalized Collector Current vs. Distance between Device and Reflector

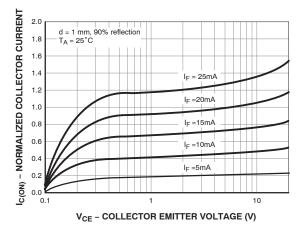


Figure 4. Normalized Collector Current vs. Collector to Emitter Voltage

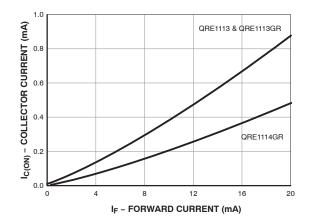


Figure 3. Collector Current vs. Forward Current

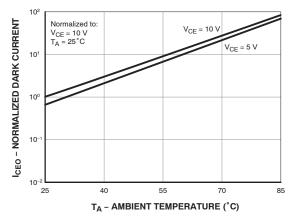


Figure 5. Collector Emitter Dark Current (Normalized) vs. Ambient Temperature

## TYPICAL PERFORMANCE CURVES (Continued)

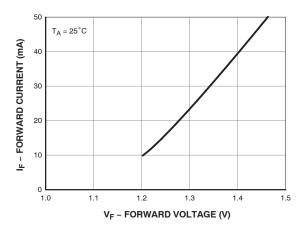


Figure 6. Forward Current vs. Forward Voltage

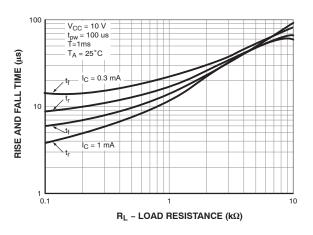


Figure 7. Rise and Fall Time vs. Load Resistance

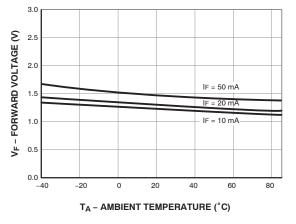


Figure 8. Forward Voltage vs. Ambient Temperature

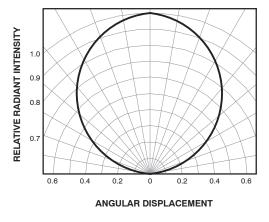
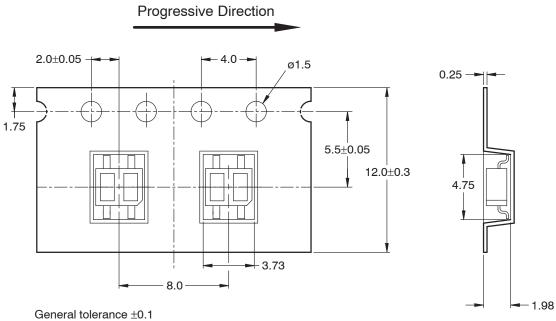


Figure 9. Radiation Diagram

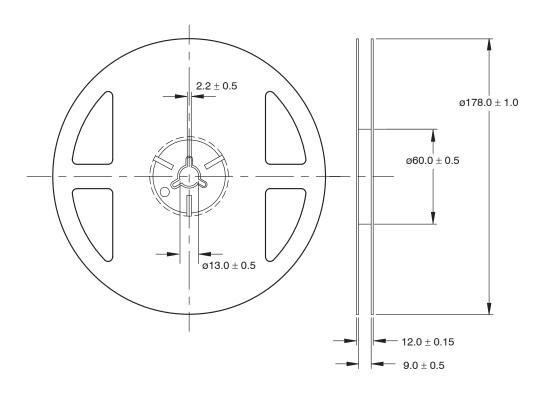
## TAPING DIMENSIONS FOR GR OPTION



Dimensions in mm









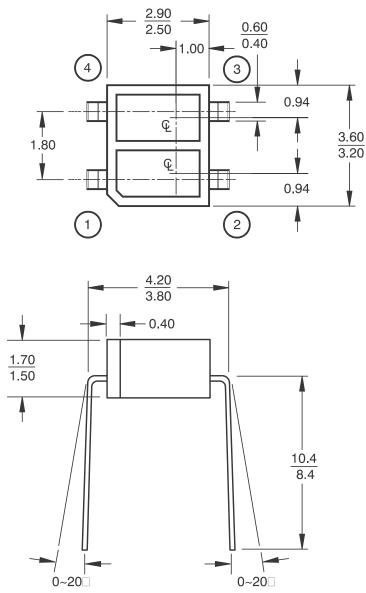
#### **Precautionary Notes**

- 1. Refer to application note AND8003/D, "Storage and Handling of Dry Packed Surface Mounted Devices" for details of handling procedure.
- Product soldering terminals are silver plated and oxidization may occur with prolonged exposure to ambient environment. Oxidized terminal
  may have poor solderability performance. Keep unsealed devices in moisture barrier bag sealed with desiccant or in dry cabinet at <5%
  relative humidity.</li>
- Store PCB in sealed moisture barrier bag together with desiccant or store in dry cabinet at <5% relative humidity. Mounted device that has been exposed to ambient environment for long period of time may suffer moisture related damage if PCB is subjected to subsequent high temperature processes.



#### REFLECTIVE RECTANGULAR THROUGH HOLE CASE 100AQ ISSUE O

DATE 30 SEP 2016



Notes:

1. Dimensions for all drawings are in millimeters.

2. Tolerance of ±0.15mm on all non-nominal dimensions

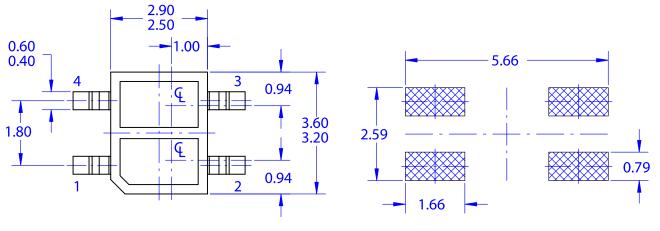
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#### ARUSM-313 / REFLECTIVE RECTANGULAR SURFACE MOUNT CASE 100CY

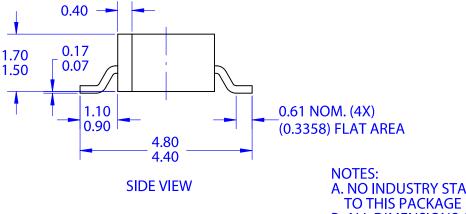
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**TOP VIEW** 

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